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Hex Level Shifter for TTL to CMOS or CMOS to CMOS

The MC14504B is a hex non-inverting level shifter using CMOS technology. The level shifter will shift a TTL signal to CMOS logic levels for any CMOS supply voltage between 5 and 15 volts. A control input also allows interface from CMOS to CMOS at one logic level to another logic level: Either up or down level translating is accomplished by selection of power supply levels V_{DD} and V_{CC} . The V_{CC} level sets the input signal levels while V_{DD} selects the output voltage levels.

Features

- UP Translates from a Low to a High Voltage or DOWN Translates from a High to a Low Voltage
- Input Threshold Can Be Shifted for TTL Compatibility
- No Sequencing Required on Power Supplies or Inputs for Power Up or Power Down
- $\bullet~$ 3 to 18 Vdc Operation for V_{DD} and V_{CC}
- Diode Protected Inputs to V_{SS}
- Capable of Driving Two Low–Power TTL Loads or One Low–Power Schottky TTL Load Over the Rated Temperature Range
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in}	Input Voltage Range (DC or Transient)	-0.5 to +18.0	V
V _{out}	Output Voltage Range (DC or Transient)	–0.5 to V _{DD} + 0.5	V
I _{in} , I _{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
PD	Power Dissipation, per Package (Note 1)	500	mW
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature (8–Second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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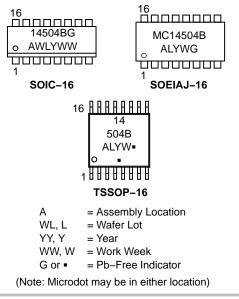
http://onsemi.com



PIN ASSIGNMENT

V _{CC} [1●		I V _{DD}
V _{CC} [A _{out} [2	15] F _{out}
A _{in} [3	14] F _{in}
B _{out} [4	13] MODE
B _{in} [5	12] E _{out}
C _{out} [6	11] E _{in}
C _{in} [7	10] D _{out}
V _{SS} [8	9] D _{in}

MARKING DIAGRAMS



ORDERING INFORMATION

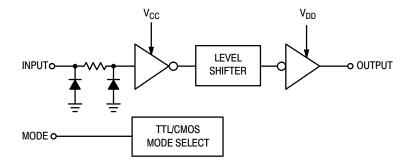
See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \le (V_{in} \text{ or } V_{out}) \le V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

LOGIC DIAGRAM



Mode Select	Input Logic Levels	Output Logic Levels
1 (V _{CC})	TTL	CMOS
0 (V _{SS})	CMOS	CMOS

1/6 of package shown.

ORDERING INFORMATION

Device	Package	Shipping [†]		
MC14504BDG	SOIC-16	48 Units / Rail		
NLV14504BDG*	(Pb-Free)			
MC14504BDR2G	SOIC-16	2500 Units / Tape & Reel		
NLV14504BDR2G*	(Pb-Free)			
MC14504BDTG	TSSOP-16	96 Units / Rail		
NLV14504BDTG*	(Pb-Free)			
MC14504BDTR2G	TSSOP-16	2500 Units / Tape & Reel		
NLV14504BDTR2G*	(Pb-Free)			
MC14504BFELG	SOEIAJ-16 (Pb-Free)	2000 Units / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

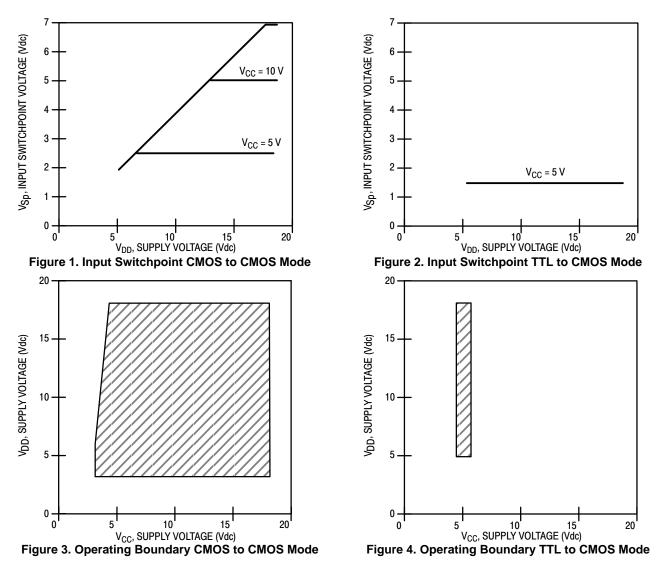
Characteristic			v	v.	- 5	5°C		25°C		125	o°C	
		Symbol	V _{CC} Vdc	V _{DD} Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Мах	Unit
Output Voltage V _{in} = 0 V	"0" Level	V _{OL}	_ _ _	5.0 10 1 5	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
$V_{in} = V_{CC}$	"1" Level	V _{OH}	_ _ _	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
Input Voltage $(V_{OL} = 1.0 \text{ Vdc}) \text{ TTL-CMOS}$ $(V_{OL} = 1.5 \text{ Vdc}) \text{ TTL-CMOS}$ $(V_{OL} = 1.0 \text{ Vdc}) \text{ CMOS-CMO}$ $(V_{OL} = 1.5 \text{ Vdc}) \text{ CMOS-CMO}$ $(V_{OL} = 1.5 \text{ Vdc}) \text{ CMOS-CMO}$	DS	V _{IL}	5.0 5.0 5.0 5.0 10	10 15 10 15 15	- - - -	0.8 0.8 1.5 1.5 3.0	- - - -	1.3 1.3 2.25 2.25 4.5	0.8 0.8 1.5 1.5 3.0	- - - -	0.8 0.8 1.4 1.5 2.9	Vdc
Input Voltage $(V_{OH} = 9.0 \text{ Vdc}) \text{ TTL-CMOS}$ $(V_{OH} = 13.5 \text{ Vdc}) \text{ TTL-CMO}$ $(V_{OH} = 9.0 \text{ Vdc}) \text{ CMOS-CM}$ $(V_{OH} = 13.5 \text{ Vdc}) \text{ CMOS-CM}$ $(V_{OH} = 13.5 \text{ Vdc}) \text{ CMOS-CM}$	S OS MOS	VIH	5.0 5.0 5.0 5.0 10	10 15 10 15 15	2.0 2.0 3.6 3.6 7.1	- - - -	2.0 2.0 3.5 3.5 7.0	1.5 1.5 2.75 2.75 5.5	- - - -	2.0 2.0 3.5 3.5 7.0	- - - -	Vdc
Output Drive Current $(V_{OH} = 2.5 \text{ Vdc})$ $(V_{OH} = 4.6 \text{ Vdc})$ $(V_{OH} = 9.5 \text{ Vdc})$ $(V_{OH} = 13.5 \text{ Vdc})$	Source	I _{OH}	- - - -	5.0 5.0 10 15	- 3.0 -0.64 - 1.6 - 4.2	- - - -	- 2.4 -0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	- - - -	- 1.7 -0.36 - 0.9 - 2.4	- - - -	mAdc
(V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc)	Sink	I _{OL}	_ _ _	5.0 10 15	0.64 1.6 4.2	_ _ _	0.51 1.3 3.4	0.88 2.25 8.8	_ _ _	0.36 0.9 2.4	- - -	mAdc
Input Current		l _{in}	-	15	-	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
Input Capacitance ($V_{in} = 0$)		C _{in}	-	-	-	-	-	5.0	7.5	-	-	pF
Quiescent Current (Per Package) CMOS–CMOS Mode		I _{DD} or I _{CC}	- - -	5.0 10 15	- - -	0.05 0.10 0.20	- - -	0.0005 0.0010 0.0015	0.05 0.10 0.20	- - -	1.5 3.0 6.0	μAdc
Quiescent Current (Per Package) TTL–CMOS Mode		I _{DD}	5.0 5.0 5.0	5.0 10 15	_ _ _	0.5 1.0 2.0	- - -	0.0005 0.0010 0.0015	0.5 1.0 2.0	- - -	3.8 7.5 15	μAdc
Quiescent Current (Per Package) TTL–CMOS Mode		Icc	5.0 5.0 5.0	5.0 10 15	- - -	5.0 5.0 5.0	- - -	2.5 2.5 2.5	5.0 5.0 5.0	- - -	6.0 6.0 6.0	mAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

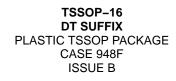
SWITCHING CHARACTERISTICS (CL = 50 pF, TA = 25° C)

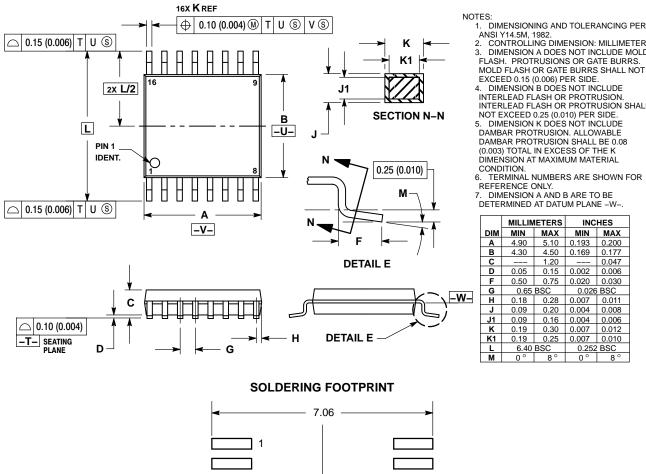
			N/	v		Limits		
Characteristic	Symbol Shifting Mode			V _{DD} Vdc	Min	Typ (Note 3)	Max	Unit
Propagation Delay, High to Low	t _{PHL}	TTL – CMOS	5.0	10	-	140	280	ns
		$V_{DD} > V_{CC}$	5.0	15	-	140	280	
		CMOS – CMOS	5.0	10	-	120	240	
		$V_{DD} > V_{CC}$	5.0	15	-	120	240	
			10	15	-	70	140	
		CMOS – CMOS	10	5.0	-	185	370	
		$V_{CC} > V_{DD}$	15	5.0	-	185	370	
			15	10	-	175	350	
Propagation Delay, Low to High	t _{PLH}	TTL – CMOS	5.0	10	-	170	340	ns
		$V_{DD} > V_{CC}$	5.0	15	-	160	320	
		CMOS – CMOS	5.0	10	-	170	340	
		$V_{DD} > V_{CC}$	5.0	15	-	170	340	
			10	15	-	100	200	
		CMOS – CMOS	10	5.0	-	275	550	
		$V_{CC} > V_{DD}$	15	5.0	-	275	550	
			15	10	-	145	290	
Output Rise and Fall Time	t _{TLH} , t _{THL}	ALL	-	5.0	-	100	200	ns
			-	10	-	50	100	
			-	15	-	40	80	

3. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



PACKAGE DIMENSIONS





16X 1.26

16X 0.36 A NOTES: 1. DIMENSIONING AND TOLERANCING PER

 ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: MILLIMETER.
DIMENSION A DOES NOT INCLUDE MOLT
PLASH. PROTRUSIONS OR GATE BURRS. FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL

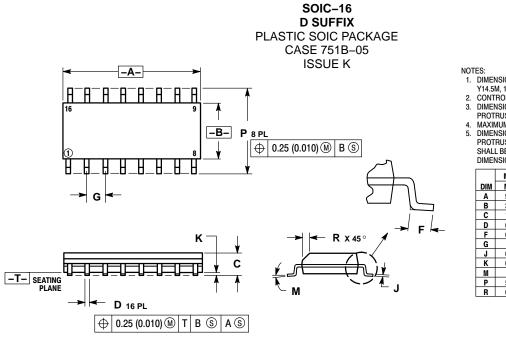
	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
в	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
н	0.18	0.28	0.007	0.011	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
Κ	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40		0.252	BSC	
М	0 °	8 °	0 °	8 °	

0.65 PITCH

A

DIMENSIONS: MILLIMETERS

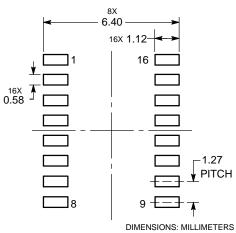
PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHAIL IN E0.127 (0.005) TOTAL IN EXCESS OF THE D SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

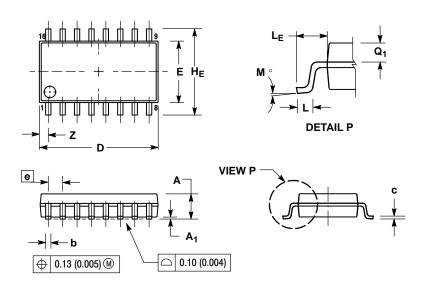
	MILLIN	IETERS	INC	HES			
DIM	MIN	MAX	MIN	MAX			
Α	9.80	10.00	0.386	0.393			
В	3.80	4.00	0.150	0.157			
С	1.35	1.75	0.054	0.068			
D	0.35	0.49	0.014	0.019			
F	0.40	1.25	0.016	0.049			
G	1.27	BSC	0.050) BSC			
J	0.19	0.25	0.008	0.009			
K	0.10	0.25	0.004	0.009			
М	0 °	7°	0 °	7°			
Ρ	5.80	6.20	0.229	0.244			
R	0.25	0.50	0.010	0.019			

SOLDERING FOOTPRINT



PACKAGE DIMENSIONS

SOEIAJ-16 **F SUFFIX** PLASTIC EIAJ SOIC PACKAGE **CASE 966 ISSUE A**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI DIMENSIO Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE
- MEASURED AT THE PARTING LINE, MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. . TERMINAL NUMBERS ARE SHOWN FOR
- THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) 5 TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α		2.05		0.081	
A ₁	0.05	0.20	0.002	0.008	
b	0.35	0.50	0.014	0.020	
С	0.10	0.20	0.007	0.011	
D	9.90	10.50	0.390	0.413	
Е	5.10	5.45	0.201	0.215	
e	1.27	BSC	0.050	BSC	
HE	7.40	8.20	0.291	0.323	
L	0.50	0.85	0.020	0.033	
LE	1.10	1.50	0.043	0.059	
М	0 °	10 °	0 °	10 °	
Q1	0.70	0.90	0.028	0.035	
Z		0.78		0.031	

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